# **Amendments to the Claims:**

This listing of claims will replace all prior versions, and listing, of claims in the application:

## **Listing of Claims:**

- 1-64. Cancelled.
- 65. (currently amended) A device comprising a nanowire, an electrical contact, and an a sacrificial layer between at least a portion of the nanowire and the electrical contact, ohmic contact electrically coupling the nanowire and the electrical contact, wherein the ohmic contacts acrificial layer comprises at least one metal silicide.
- 66. (previously presented) The device of claim 65, wherein the at least one metal silicide comprises titanium silicide.
- 67. (previously presented) The device of claim 65, wherein the at least one metal silicide comprises nickel silicide.
  - 68. Cancelled.
- 69. (currently amended) The device of claim 6865, wherein the sacrificial layer comprises poly or amorphous doped silicon.
  - 70. Cancelled.

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- 71. (previously presented) The device of claim 70, wherein the nanowire has at least one dimension less than or equal to 500 nm.
- 72. (previously presented) The device of claim 70, wherein the nanowire has at least one dimension less than or equal to 200 nm.
- 73. (previously presented) The device of claim 70, wherein the nanowire comprises silicon.
  - 74. Cancelled.
- 75. (currently amended) A device comprising one or more nanowire which is electrically coupled to an electrode contact at a <u>sacrificial layer comprising a</u> metal silicide <u>junction</u> which sacrificial layer is positioned between the nanowire and the <u>electrode contact</u>.
- 76. (previously presented) The device of claim 75, wherein the metal is selected from the group comprising titanium, platinum, nickel, chromium, aluminum, copper and gold.

### 77-78. Cancelled.

79. (currently amended) The device of <u>claims-claim</u> 75, wherein the device comprises a nanosensor.

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#### 80. Cancelled.

- 81. (previously presented) The device of claim 79, wherein the nanosensor comprises an array for detection of a change in charge, the array comprising a plurality of nanowires, which nanowires each comprise one or more functional group, which functional group undergoes a change in charge when exposed to a component of interest.
- 82. (currently amended) A method of reducing an ohmic contact resistance at a junction between a nanowire and an electrical contact comprising forming a sacrificial layer between said nanowire and said electrical contact, and forming said junction from at least one metal silicide in the sacrificial layer.
- 83. (previously presented) The method of claim 82, wherein the at least one metal silicide comprises titanium silicide.
- 84. (previously presented) The method of claim 82, wherein the at least one metal silicide comprises nickel silicide.
- 85. (previously presented) The method of claim 82, wherein the at least one metal silicide comprises platinum silicide.
- 86. (previously presented) The method of claim 82, wherein the at least one metal silicide comprises tantalum silicide.

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### 87. Cancelled.

- 88. (currently amended) The method of claim 8782, wherein the nanowire is electrically coupled to the electrode contact via said sacrificial layer.
- 89. (currently amended) The method of claim 82, wherein the junction metal silicide comprises a metal selected from the group comprising titanium, platinum, chromium, nickel, aluminum, copper and gold.
- 90. (currently amended) The method of claim 82, wherein the junction sacrificial layer further comprises one or more dopant materials.
  - 91. Cancelled.
- 92. (new) A device comprising one or more nanowire, an electrode contact, and a first layer of amorphous silicon or polysilcon between the nanowire and the electrode contact, wherein the first layer comprises at least one metal silicide.
- 93. (new) The device of claim 92, wherein the nanowire is electrically coupled to the electrode contact via said first layer.